CLAIMS

1. A test board de-embedding method to improve RF measurements accuracy on an automatic testing equipment for IC wafers, wherein each wafer includes a device under test located on a wafer die plane and being contacted by probecard needles of a probecard that is coupled to a configuration board through a probe interface board, the method including the following phases:

performing an automatic calibration phase of said testing equipment up to an internal plane inside said automatic testing equipment;

performing a calibration plane transfer up to a plane of said configuration board; performing a test boards de-embedding phase up to the wafer die plane.

- 2. The method according to claim 1, wherein said calibration plane transfer is performed by using a predetermined number of calibration standard loads on said wafer.
- 3. The method according to claim 1, wherein said calibration plane transfer is performed by using at least three calibration standard loads on said wafer.
- 4. The method according to claim 2, wherein said calibration standard loads are coaxial OSL (Open, Short, Load) standards.
- 5. The method according to claim 2, wherein said test boards de-embedding phase is performed using the same calibration standards realized on said wafer.
- 6. The method according to claim 2, said calibration standards have been realized directly using the pad portions of the integrated device realized on said wafer.

- 7. The method according to claim 2, wherein said used loads are: Open circuit, Short circuit and a 50 Ohm load, thus forming OSL (Open, Short, Load) calibration standards.
- 8. The method according to claim 2, wherein said calibration standards are defined on said wafer providing specific metal levels masks and a passivation mask for the device under test.
- 9. The method according to claim 1, wherein said probecard and said probe interface board depend on the device under test.
- 10. A method to improve RF measurements accuracy on an automatic testing equipment for IC wafers by implementing a test board de-embedding phase, wherein each wafer includes a device under test located on a wafer die plane and being contacted by probecard needles of a probecard that is coupled to a configuration board through a probe interface board, the method including the following phases:

performing an automatic calibration phase of said testing equipment up to an internal plane located inside said automatic testing equipment;

performing a calibration plane transfer up to a plane of said configuration board using a predetermined number of calibration standard loads realized on said wafer;

performing a test boards de-embedding phase up to the wafer die plane.

- 11. The method according to claim 10, wherein said calibration standard loads on said wafer are at least three.
- 12. The method according to claim 10, wherein said calibration standard loads are coaxial OSL (Open, Short, Load) standards.

- 13. The method according to claim 10, wherein said test boards de-embedding phase is performed using the same calibration standards realized on said wafer.
- 14. The method according to claim 10, said calibration standards have been realized directly using the pad portions of the integrated device realized on said wafer.
- 15. The method according to claim 10, wherein said loads used are: Open circuit, Short circuit and a 50 Ohm load, thus forming OSL (Open, Short, Load) calibration standards.
- 16. The method according to claim 10, wherein said calibration standards are defined on said wafer providing specific metal levels masks and a passivation mask for the device under test.
- 17. The method according to claim 10, wherein said probecard and said probe interface board depend on the device under test.
- 18. A method to improve RF measurements accuracy on an automatic testing equipment for IC wafers including at least a device or circuit under test located on a wafer die plane, the wafer being contacted by probecard needles of a probecard that is coupled to a configuration board of said equipment through a probe interface board, the method including the following phases:

performing a calibration phase of said testing equipment up to an internal plane located inside said automatic testing equipment;

performing a calibration plane transfer up to a plane of said configuration board using a predetermined number of calibration standard loads realized on said wafer:

performing a test boards de-embedding phase up to the wafer die plane.

- 19. The method according to claim 18, wherein at least three calibration standard loads on said wafer are used for said calibration plane transfer.
- 20. The method according to claim 18, wherein said calibration standard loads are coaxial OSL (Open, Short, Load) standards.
- 21. The method according to claim 18, wherein said test boards de-embedding phase is performed using the same calibration standards realized on said wafer.
- 22. The method according to claim 18, said calibration standards have been realized directly using the pad portions of the integrated device realized on said wafer.
- 23. The method according to claim 18, wherein said used loads are: Open circuit, Short circuit and a 50 Ohm load, thus forming OSL (Open, Short, Load) calibration standards.
- 24. The method according to claim 18, wherein said calibration standards are defined on said wafer providing specific metal levels masks and a passivation mask for the device under test.
- 25. The method according to claim 18, wherein said probecard and said probe interface board depend on the device under test.